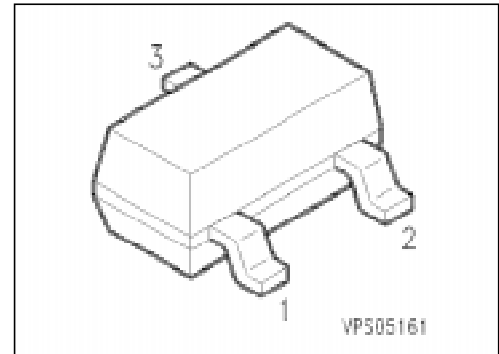


## PNP Silicon AF Transistors

**BCW 61**  
**BCX 71**

- For AF input stages and driver applications
- High current gain
- Low collector-emitter saturation voltage
- Low noise between 30 Hz and 15 kHz
- Complementary types: BCW 60, BCX 70 (NPN)



Type	Marking	Ordering Code (tape and reel)	Pin Configuration			Package <sup>1)</sup>
			1	2	3	
BCW 61 A	BAs	Q62702-C452	B	E	C	SOT-23
BCW 61 B	BBs	Q62702-C1585				
BCW 61 C	BCs	Q62702-C1478				
BCW 61 D	BDs	Q62702-C1556				
BCW 61 FF	BFs	Q62702-C1890				
BCW 61 FN	BNs	Q62702-C1891				
BCX 71G	BGs	Q62702-C1482				
BCX 71H	BHs	Q62702-C1586				
BCX 71J	BJs	Q62702-C1554				
BCX 71 K	BKs	Q62702-C1654				

<sup>1)</sup> For detailed information see chapter Package Outlines.

## Maximum Ratings

Parameter	Symbol	Values			Unit
		BCW 61	BCW 61 FF	BCX 71	
Collector-emitter voltage	$V_{CE0}$	32	32	45	V
Collector-base voltage	$V_{CB0}$	32	32	45	
Emitter-base voltage	$V_{EB0}$	5			
Collector current	$I_C$	100			mA
Peak collector current	$I_{CM}$	200			
Peak base current	$I_{BM}$	200			
Total power dissipation, $T_s = 71\text{ °C}$	$P_{tot}$	330			mW
Junction temperature	$T_j$	150			°C
Storage temperature range	$T_{stg}$	- 65 ... + 150			

## Thermal Resistance

Junction - ambient <sup>1)</sup>	$R_{th JA}$	≤ 310	K/W
Junction - soldering point	$R_{th JS}$	≤ 240	

<sup>1)</sup> Package mounted on epoxy pcb 40 mm × 40 mm × 1.5 mm/6 cm<sup>2</sup> Cu.

## Electrical Characteristics

at  $T_A = 25\text{ °C}$ , unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

### DC characteristics

Collector-emitter breakdown voltage $I_C = 10\text{ mA}$ BCW 61, BCW 61 FF BCX 71	$V_{(BR)CE0}$	32 45	— —	— —	V
Collector-base breakdown voltage $I_C = 10\text{ }\mu\text{A}$ BCW 61, BCW 61 FF BCX 71	$V_{(BR)CB0}$	32 45	— —	— —	
Emitter-base breakdown voltage $I_E = 1\text{ }\mu\text{A}$	$V_{(BR)EB0}$	5	—	—	
Collector cutoff current $V_{CB} = 32\text{ V}$ BCW 61, BCW 61 FF $V_{CB} = 45\text{ V}$ BCX 71 $V_{CB} = 32\text{ V}, T_A = 150\text{ °C}$ BCW 61, BCW 61 FF $V_{CB} = 45\text{ V}, T_A = 150\text{ °C}$ BCX 71	$I_{CB0}$	— — — —	— — — —	20 20 20 20	nA nA $\mu\text{A}$ $\mu\text{A}$
Emitter cutoff current $V_{EB} = 4\text{ V}$	$I_{EB0}$	—	—	20	nA
DC current gain <sup>1)</sup> $I_C = 10\text{ }\mu\text{A}, V_{CE} = 5\text{ V}$ BCW 61 A, BCX 71 G BCW 61 B, BCX 71 H BCW 61 FF, BCW 61 C, BCX 71 J BCW 61 FN, BCW 61 D, BCX 71 K $I_C = 2\text{ mA}, V_{CE} = 5\text{ V}$ BCW 61 A, BCX 71 G BCW 61 B, BCX 71 H BCW 61 FF, BCW 61 C, BCX 71 J BCW 61 FN, BCW 61 D, BCX 71 K $I_C = 50\text{ mA}, V_{CE} = 1\text{ V}$ BCW 61 A, BCX 71 G BCW 61 B, BCX 71 H BCW 61 FF, BCW 61 C, BCX 71 J BCW 61 FN, BCW 61 D, BCX 71 K	$h_{FE}$	20 30 40 100  120 180 250 380  60 80 100 110	140 200 300 460  170 250 350 500  — — — —	— — — —  220 310 460 630  — — — —	—

<sup>1)</sup> Pulse test:  $t \leq 300\text{ }\mu\text{s}, D \leq 2\%$ .

## Electrical Characteristics

at  $T_A = 25\text{ °C}$ , unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

### DC characteristics

Collector-emitter saturation voltage <sup>1)</sup> $I_C = 10\text{ mA}$ , $I_B = 0.25\text{ mA}$ $I_C = 50\text{ mA}$ , $I_B = 1.25\text{ mA}$	$V_{CEsat}$	–	0.12	0.25	V
		–	0.20	0.55	
Base-emitter saturation voltage <sup>1)</sup> $I_C = 10\text{ mA}$ , $I_B = 0.25\text{ mA}$ $I_C = 50\text{ mA}$ , $I_B = 1.25\text{ mA}$	$V_{BEsat}$	–	0.70	0.85	
		–	0.83	1.05	
Base-emitter voltage <sup>1)</sup> $I_C = 10\text{ }\mu\text{A}$ , $V_{CE} = 5\text{ V}$ $I_C = 2\text{ mA}$ , $V_{CE} = 5\text{ V}$ $I_C = 50\text{ mA}$ , $V_{CE} = 1\text{ V}$	$V_{BE(on)}$	–	0.52	–	
		0.55	0.65	0.75	
		–	0.78	–	

### AC characteristics

Transition frequency $I_C = 20\text{ mA}$ , $V_{CE} = 5\text{ V}$ , $f = 100\text{ MHz}$	$f_t$	–	250	–	MHz
Output capacitance $V_{CB} = 10\text{ V}$ , $f = 1\text{ MHz}$	$C_{obo}$	–	3	–	pF
Input capacitance $V_{CB} = 0.5\text{ V}$ , $f = 1\text{ MHz}$	$C_{ibo}$	–	8	–	
Short-circuit input impedance $I_C = 2\text{ mA}$ , $V_{CE} = 5\text{ V}$ , $f = 1\text{ kHz}$ BCW 61 A, BCX 71 G BCW 61 B, BCX 71 H BCW 61 FF, BCW 61 C, BCX 71 J BCW 61 FN, BCW 61 D, BCX 71 K	$h_{11e}$	–	2.7	–	k $\Omega$
		–	3.6	–	
		–	4.5	–	
		–	7.5	–	
Open-circuit reverse voltage transfer ratio $I_C = 2\text{ mA}$ , $V_{CE} = 5\text{ V}$ , $f = 1\text{ kHz}$ BCW 61 A, BCX 71 G BCW 61 B, BCX 71 H BCW 61 FF, BCW 61 C, BCX 71 J BCW 61 FN, BCW 61 D, BCX 71 K	$h_{12e}$	–	1.5	–	$10^{-4}$
		–	2.0	–	
		–	2.0	–	
		–	3.0	–	

<sup>1)</sup> Pulse test:  $t \leq 300\text{ }\mu\text{s}$ ,  $D \leq 2\%$ .

## Electrical Characteristics

at  $T_A = 25\text{ °C}$ , unless otherwise specified.

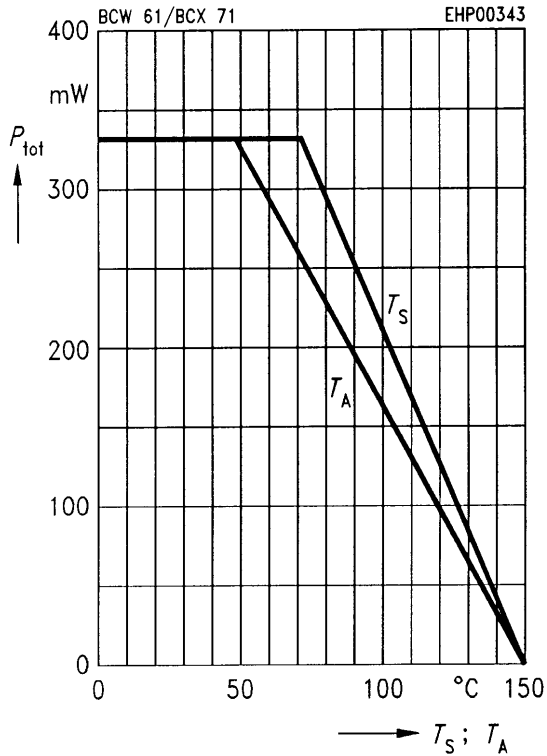
Parameter	Symbol	Values			Unit
		min.	typ.	max.	

### AC characteristics

Short-circuit forward current transfer ratio $I_C = 2\text{ mA}$ , $V_{CE} = 5\text{ V}$ , $f = 1\text{ kHz}$ BCW 61 A, BCX 71 G BCW 61 B, BCX 71 H BCW 61 FF, BCW 61 C, BCX 71 J BCW 61 FN, BCW 61 D, BCX 71 K	$h_{21e}$	–	200	–	–
Open-circuit output admittance $I_C = 2\text{ mA}$ , $V_{CE} = 5\text{ V}$ , $f = 1\text{ kHz}$ BCW 61 A, BCX 71 G BCW 61 B, BCX 71 H BCW 61 FF, BCW 61 C, BCX 71 J BCW 61 FN, BCW 61 D, BCX 71 K	$h_{22e}$	–	18	–	$\mu\text{S}$
Noise figure $I_C = 0.2\text{ mA}$ , $V_{CE} = 5\text{ V}$ , $R_S = 2\text{ k}\Omega$ $f = 1\text{ kHz}$ , $\Delta f = 200\text{ Hz}$ BCW 61 A to BCX 71 K BCW 61 FF, BCW 61 FN	$F$	–	2	–	dB
Equivalent noise voltage $I_C = 0.2\text{ mA}$ , $V_{CE} = 5\text{ V}$ , $R_S = 2\text{ k}\Omega$ $f = 10\text{ Hz} \dots 50\text{ Hz}$ BCW 61 FF, BCW 61 FN	$V_n$	–	–	0.11	$\mu\text{V}$

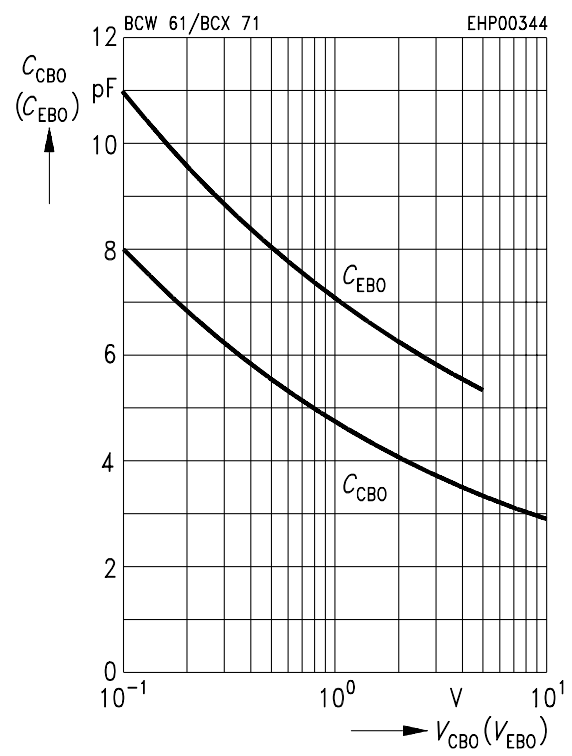
### Total power dissipation $P_{tot} = f(T_A^*; T_S)$

\* Package mounted on epoxy



### Collector-base capacitance $C_{CB0} = f(V_{CB0})$

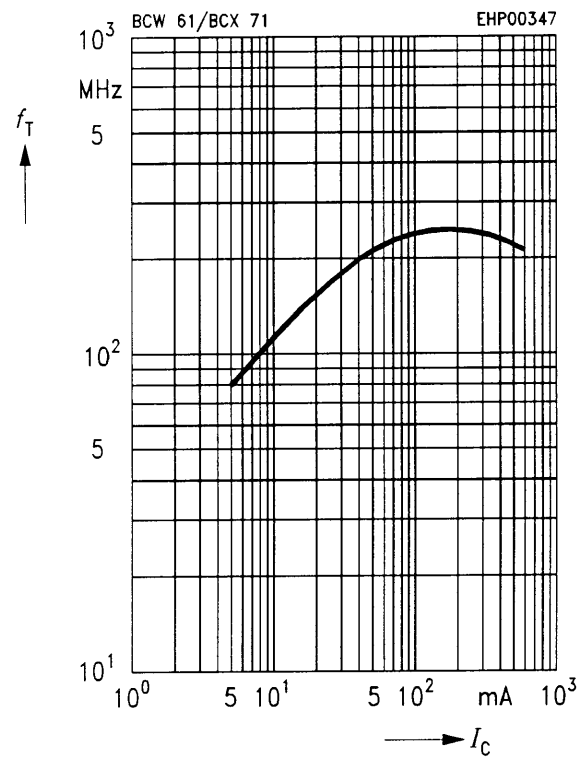
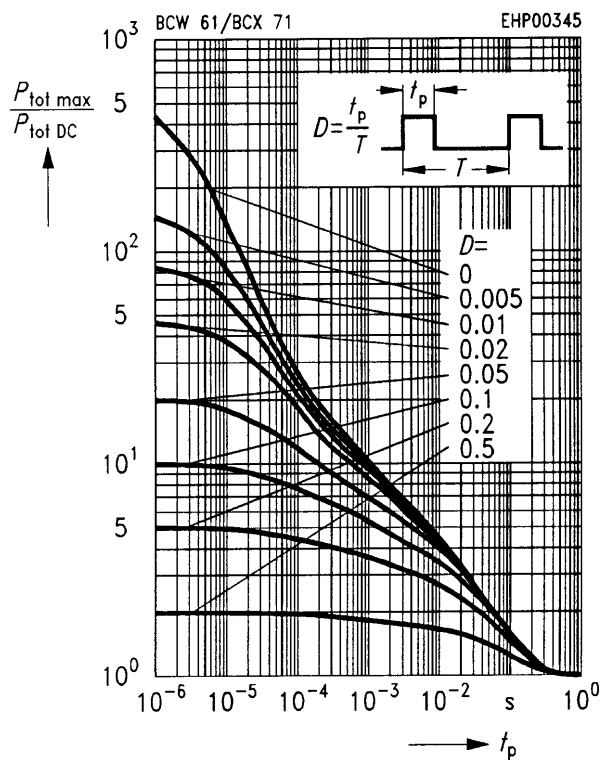
### Emitter-base capacitance $C_{EB0} = f(V_{EB0})$



### Permissible pulse load $P_{tot max}/P_{tot DC} = f(t_p)$

### Transition frequency $f_T = f(I_C)$

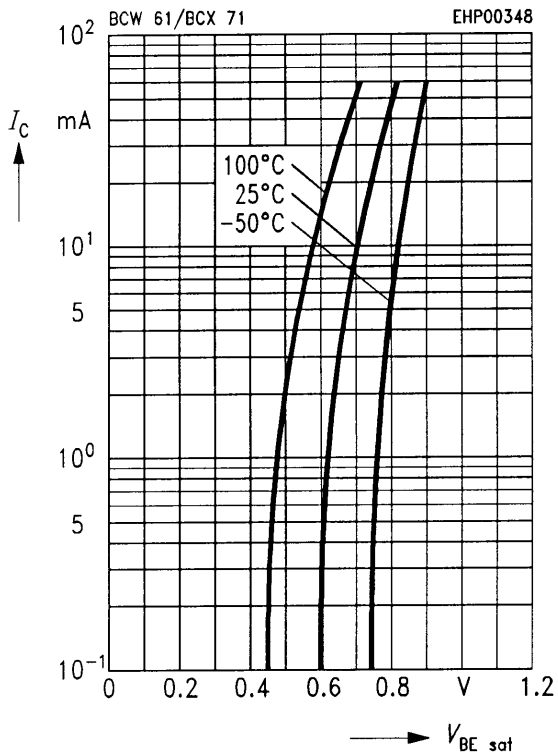
$V_{CE} = 5 V$



**Base-emitter saturation voltage**

$I_C = f(V_{BEsat})$

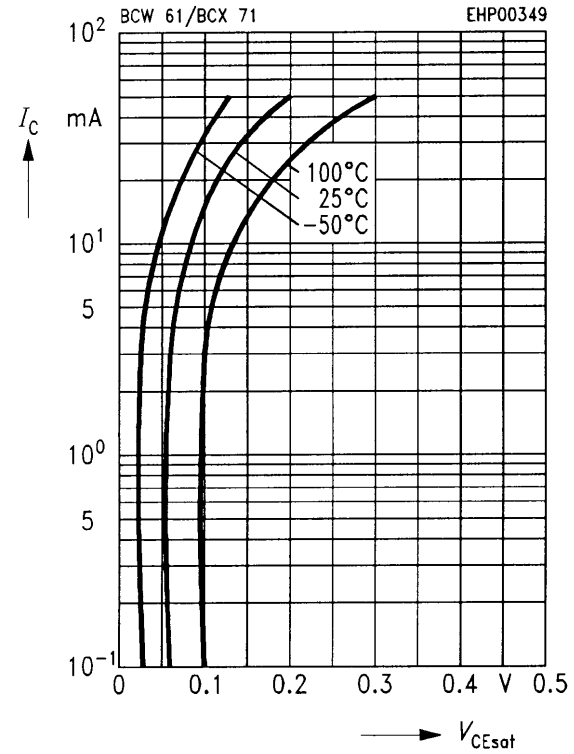
$h_{FE} = 40$



**Collector-emitter saturation voltage**

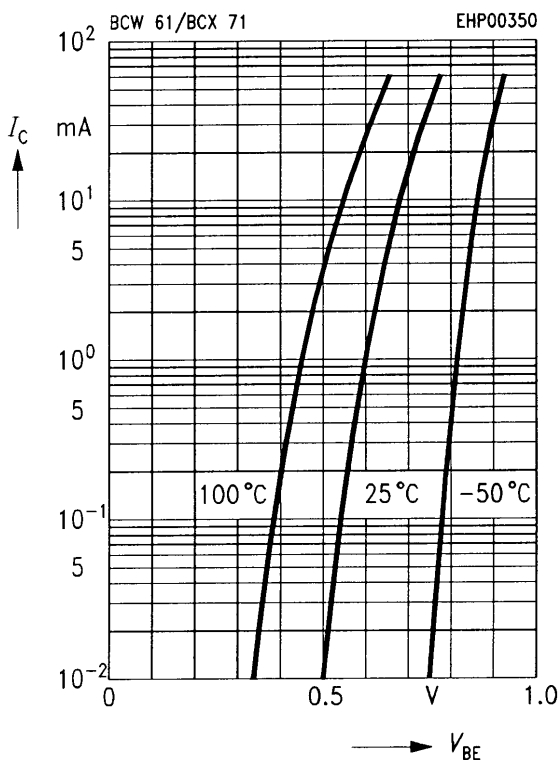
$I_C = f(V_{CEsat})$

$h_{FE} = 40$



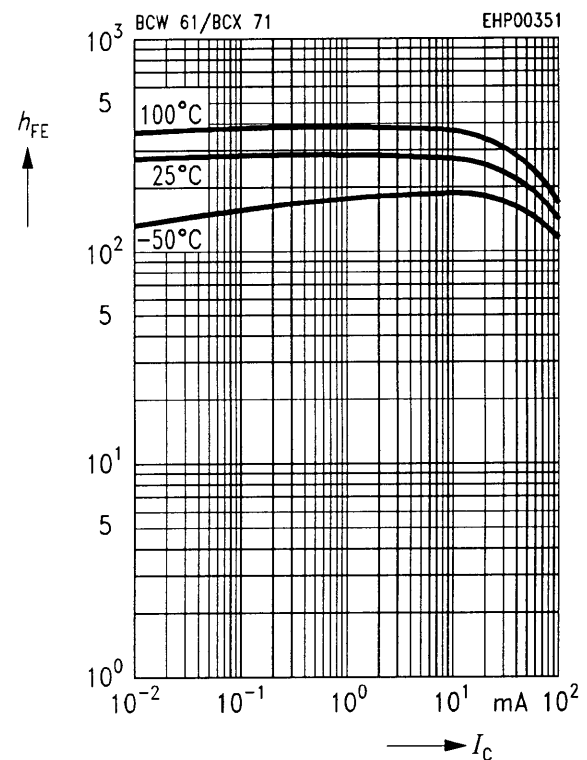
**Collector current  $I_C = f(V_{BE})$**

$V_{CE} = 5 V$

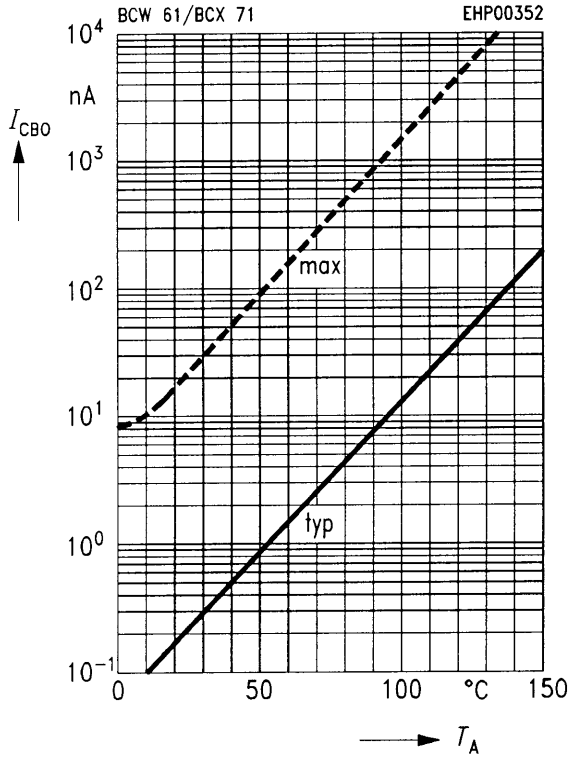


**DC current gain  $h_{FE} = f(I_C)$**

$V_{CE} = 5 V$

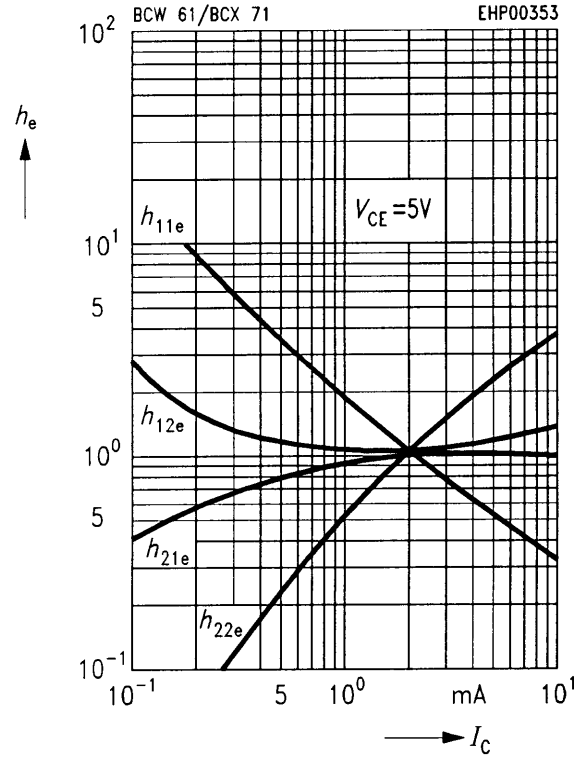


Collector cutoff current  $I_{CB0} = f(T_A)$



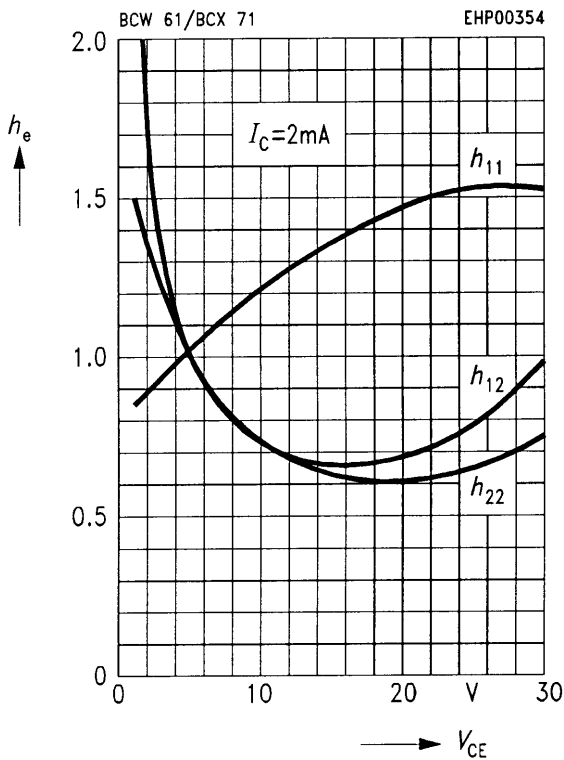
h parameter  $h_e = f(I_C)$

$V_{CE} = 5 V$



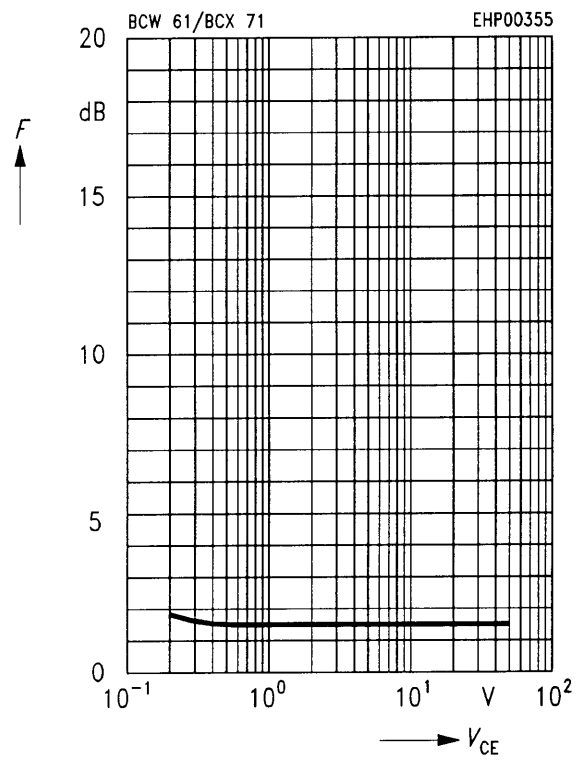
h parameter  $h_e = f(V_{CE})$

$I_C = 2 mA$



Noise figure  $F = f(V_{CE})$

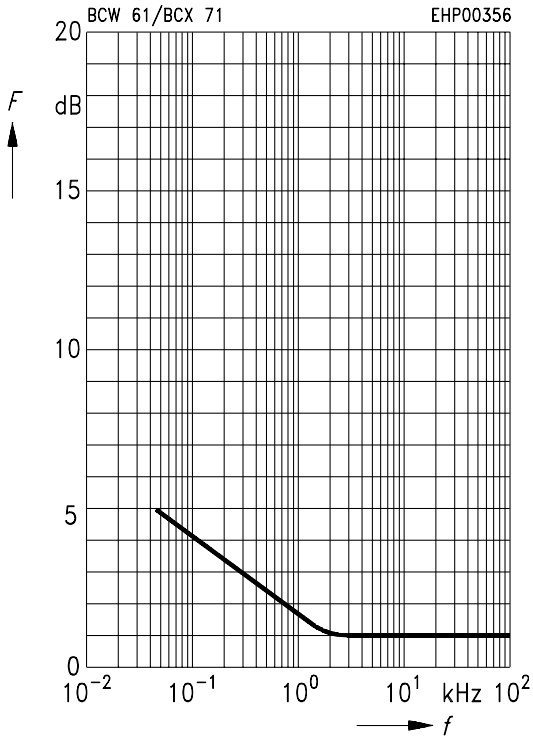
$I_C = 0.2 mA, R_S = 2 k\Omega, f = 1 kHz$





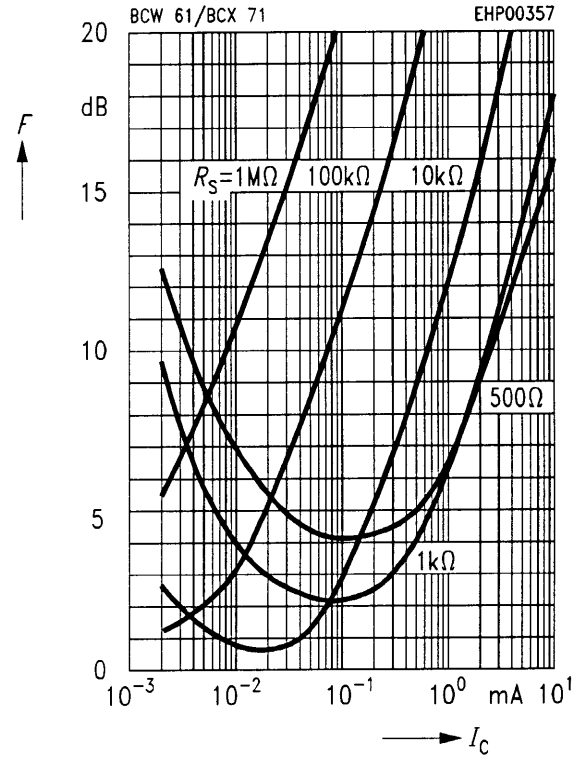
**Noise figure  $F = f(f)$**

$I_C = 0.2 \text{ mA}, R_S = 2 \text{ k}\Omega, V_{CE} = 5 \text{ V}$



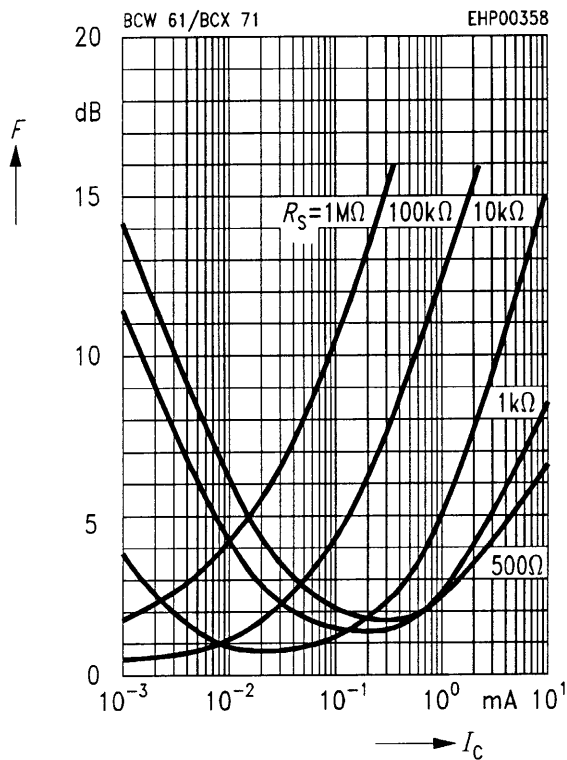
**Noise figure  $F = f(I_C)$**

$V_{CE} = 5 \text{ V}, f = 120 \text{ Hz}$



**Noise figure  $F = f(I_C)$**

$V_{CE} = 5 \text{ V}, f = 1 \text{ kHz}$



**Noise figure  $F = f(I_C)$**

$V_{CE} = 5 \text{ V}, f = 10 \text{ kHz}$

